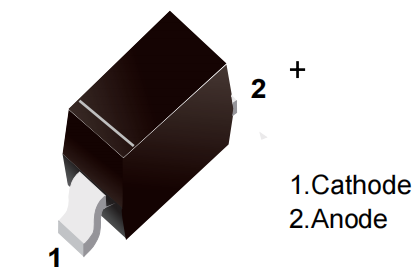


Features

- Low Forward Voltage Drop.
- Guard Ring Construction For Transient Protection.
- Negligible Reverse Recovery Time.
- Low Reverse Capacitance.



■ Simplified outline(SOD323)

Top View - ○ —  — ○ +

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	1N5819WS-L	1N5819BWS-L	1N5819CWS-L	Unit
Peak Repetitive Peak reverse voltage	V_{RR}				
Working Peak	V_{RWM}	40	30	20	V
DC Reverse Voltage	V_R				
RMS Reverse Voltage	$V_{R(RMS)}$	28	21	14	V
Forward Continuous Current	I_F	350			mA
Repetitive Peak Forward Current @ $t \leq 1.0s$	I_{FRM}	1.5			A
Power Dissipation	P_d	400			mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	300			°C/W
Storage temperature	T_{stg}	-65~+125			°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage 1N5819WS-L 1N5819BWS-L 1N5819CWS-L	$V_{(BR)R}$	40 30 20			V	$I_R=10\mu A$ $I_R=10\mu A$ $I_R=10\mu A$
Forward voltage	V_F			0.37 0.60	V	$I_F=20mA$ $I_F=200mA$
Reverse current 1N5819WS-L 1N5819BWS-L 1N5819CWS-L	I_{RM}			5.0	μA	$V_R=30V$ $V_R=20V$ $V_R=10V$
Capacitance between terminals	C_T		50		pF	$V_R=0, f=1MHz$
Reverse Recovery Time	t_{rr}		10		ns	$I_R=I_F=200mA$ $I_{rr}=0.1 \cdot I_R, R_L=100\Omega$

Outline Drawing – SOD323

